## Surface Mount Schottky Power Rectifier

## SOD-123 Power Surface Mount Package

The Schottky Power Rectifier employs the Schottky Barrier principle with a barrier metal that produces optimal forward voltage drop-reverse current tradeoff. Ideally suited for low voltage, high frequency rectification, or as a free wheeling and polarity protection diodes in surface mount applications where compact size and weight are critical to the system. This package provides an alternative to the leadless 34 MELF style package. These state-of-the-art devices have the following features:

- Guardring for Stress Protection
- Very Low Forward Voltage
- Epoxy Meets UL94, VO at 1/8"
- Package Designed for Optimal Automated Board Assembly

#### **Mechanical Characteristics:**

- Reel Options: 3,000 per 7 inch reel/8 mm tape
- Reel Options: 10,000 per 13 inch reel/8 mm tape
- Device Marking: B4
- Polarity Designator: Cathode Band
- Weight: 11.7 mg (approximately)
- Case: Epoxy Molded
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C max. for 10 Seconds

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	40	V
Average Rectified Forward Current (At Rated V <sub>R</sub> , T <sub>C</sub> = 115°C)	۱ <sub>0</sub>	0.5	A
Peak Repetitive Forward Current (At Rated V <sub>R</sub> , Square Wave, 20 kHz, T <sub>C</sub> = 115°C)	I <sub>FRM</sub>	1.0	A
Non–Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I <sub>FSM</sub>	5.5	A
Storage/Operating Case Temperature Range	T <sub>stg</sub> , T <sub>C</sub>	-55 to +150	°C
Operating Junction Temperature	TJ	-55 to +150	°C
Voltage Rate of Change (Rated $V_R$ , $T_J$ = 25°C)	dv/dt	1000	V/μs



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## SCHOTTKY BARRIER RECTIFIER 0.5 AMPERES 40 VOLTS



SOD-123 CASE 425 STYLE 1

#### MARKING DIAGRAM



B4 = Device Code

#### **ORDERING INFORMATION**

Device	Package	Shipping
MBR0540T1	SOD-123	3000/Tape & Reel
MBR0540T3	SOD-123	10,000/Tape & Reel

#### THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Resistance – Junction–to–Lead (Note 1.)	R <sub>tjl</sub>	118	°C/W
Thermal Resistance – Junction–to–Ambient (Note 2.)	R <sub>tja</sub>	206	

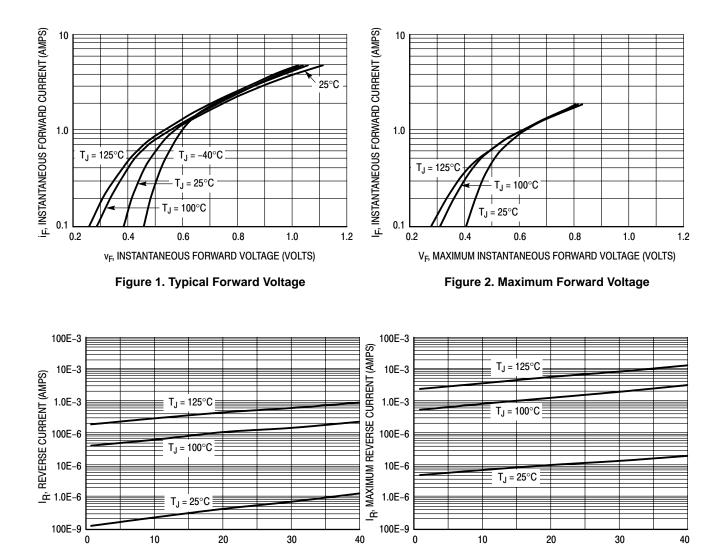
#### **ELECTRICAL CHARACTERISTICS**

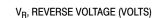
Maximum Instantaneous Forward Voltage (Note 3.)	VF	T <sub>J</sub> = 25°C	$T_J = 100^{\circ}C$	V
(i <sub>F</sub> = 0.5 A) (i <sub>F</sub> = 1 A)		0.51 0.62	0.46 0.61	
Maximum Instantaneous Reverse Current (Note 3.)	I <sub>R</sub>	T <sub>J</sub> = 25°C	T <sub>J</sub> = 100°C	μΑ
(V <sub>R</sub> = 40 V) (V <sub>R</sub> = 20 V)		20 10	13,000 5,000	

1. Mounted with minimum recommended pad size, PC Board FR4.

2. 1 inch square pad size (1 X 0.5 inch for each lead) on FR4 board.

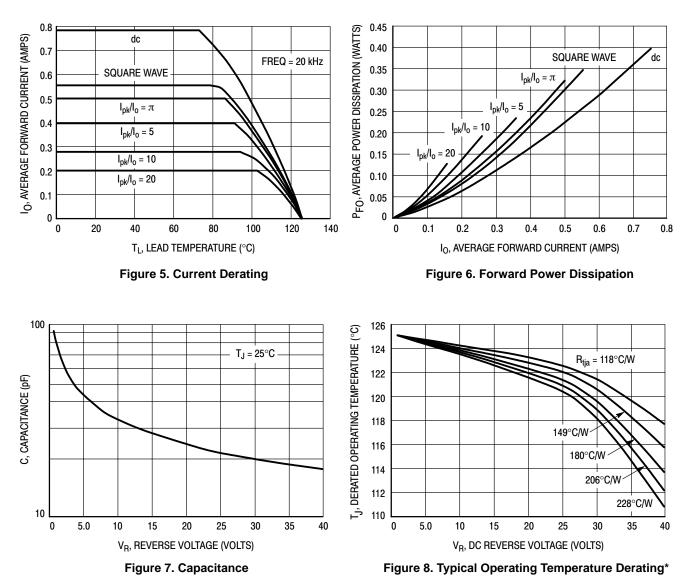
3. Pulse Test: Pulse Width  $\leq$  250 µs, Duty Cycle  $\leq$  2.0%.







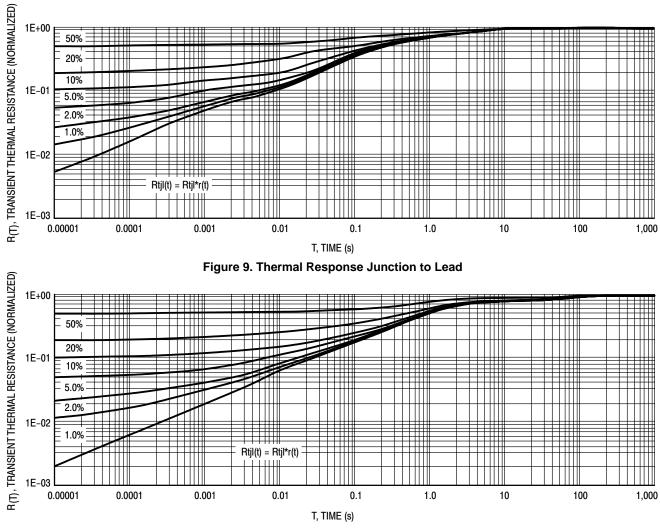


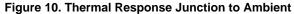


\* Reverse power dissipation and the possibility of thermal runaway must be considered when operating this device under any reverse voltage conditions. Calculations of  $T_J$  therefore must include forward and reverse power effects. The allowable operating  $T_J$  may be calculated from the equation:  $T_J = T_{Jmax} - r(t)(Pf + Pr)$  where

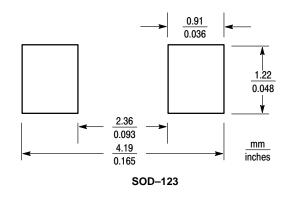
- r(t) = thermal impedance under given conditions,
- Pf = forward power dissipation, and
- Pr = reverse power dissipation

This graph displays the derated allowable  $T_J$  due to reverse bias under DC conditions only and is calculated as  $T_J = T_{Jmax} - r(t)Pr$ , where r(t) = Rthja. For other power applications further calculations must be performed.



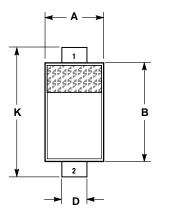


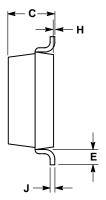
### **RECOMMENDED FOOTPRINT FOR SOD-123**



### PACKAGE DIMENSIONS

SOD-123 PLASTIC CASE 425-04 **ISSUE C** 





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

CONTROLLING D	IMENSION: INCH.
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	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.055	0.071	1.40	1.80
В	0.100	0.112	2.55	2.85
С	0.037	0.053	0.95	1.35
D	0.020	0.028	0.50	0.70
Е	0.004		0.25	
н	0.000	0.004	0.00	0.10
J		0.006		0.15
Κ	0.140	0.152	3.55	3.85

STYLE 1: PIN 1. CATHODE 2. ANODE

## <u>Notes</u>

## <u>Notes</u>

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